



60V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
60V	14mΩ @ V _{GS} = 10V	9.5
	21mΩ @ V _{GS} = 4.5V	7.7

Features and Benefits

- 100% Unclamped Inductive Switching (UIS) Test in Production— Ensures More Reliable and Robust End Application
- 0.6mm Profile—Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

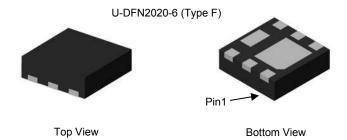
Description and Applications

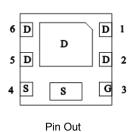
This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- DC-DC Converter
- Adaptor Switch
- Wireless Charging

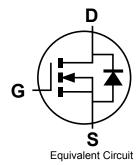
Mechanical Data

- Case: U-DFN2020-6 (Type F)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—NiPdAu over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 4
- Weight: 0.007 grams (Approximate)





Bottom View



Ordering Information (Note 4)

Part Number	Package	Quantity per Reel
DMT6012LFDF-7	U-DFN2020-6 (Type F)	3000
DMT6012LFDF-13	U-DFN2020-6 (Type F)	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1:



T12 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Date Code Hoy												
Year	2017	201	8	2019	2020	202	21	2022	2023	202	24	2025
Code	E	F		G	Н	- 1		J	K	L		M
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Site 2:



T12 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week (ex: a = week 27; z represents week 52 and 53) X = Internal code (ex: U = Monday)

Date Code Key

Year	2017	2018	2019	2020	2021	2022	2023	2024	2025
Code	7	8	9	0	1	2	3	4	5
	I.	-					-	I.	

Week	1-26	27-52	53
Code	A-Z	a-z	Z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	Т	U	V	W	X	Υ	Z



Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V_{DSS}	60	V
Gate-Source Voltage	V_{GSS}	±20	V	
Continuous Drain Current (Note 6) V _{GS} = 10V	l _D	9.5 7.6	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	60	Α
Maximum Body Diode Continuous Current		Is	2.1	Α
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	I _{SM}	60	Α	
Avalanche Current (Note 7) L = 0.1mH	I _{AS}	12.6	Α	
Avalanche Energy (Note 7) L = 0.1mH		E _{AS}	7.9	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit	
Total Dower Discination (Note 5)	$T_A = +25^{\circ}C$	Б	0.9	W	
Total Power Dissipation (Note 5)	T _A = +70°C	P_{D}	0.6		
Thermal Resistance, Junction to Ambient (Note 5)		$R_{\Theta JA}$	131	°C/W	
Total Dower Discination (Note 6)	$T_A = +25^{\circ}C$	Б	1.9	W	
Total Power Dissipation (Note 6)	T _A = +70°C	P_{D}	1.2	۷V	
Thermal Resistance, Junction to Ambient (Note 6)		$R_{\Theta JA}$	66	°C/W	
Total Power Dissipation (Note 6)	T _C = +25°C	P _D	11	W	
Thermal Resistance, Junction to Case (Note 6)		R _{eJC}	11.4	°C/W	
Operating and Storage Temperature Range		$T_{J_{I}}T_{STG}$	-55 to +150	°C	

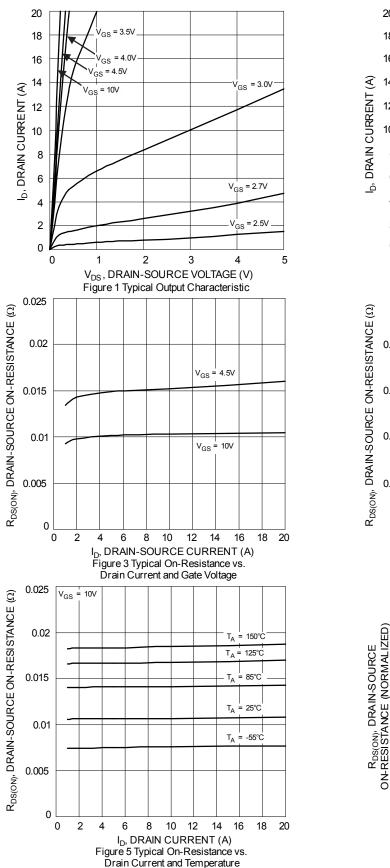
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

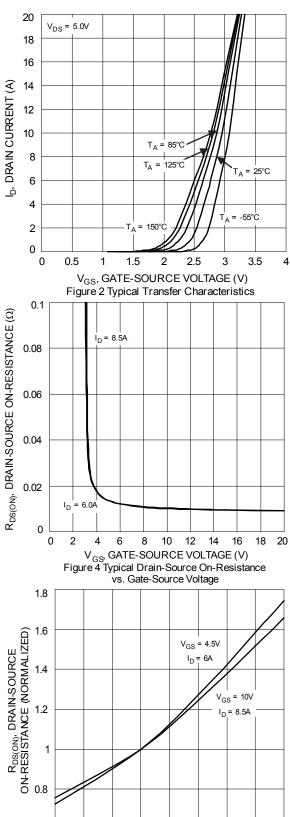
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	V _{DS} = 48V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	1.2	_	2.3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$
Static Drain-Source On-Resistance		_	10.7	14	mΩ	V _{GS} = 10V, I _D = 8.5A
Static Diain-Source On-Resistance	R _{DS(ON)}	_	15.7	21	11122	$V_{GS} = 4.5V, I_D = 6A$
Diode Forward Voltage	V _{SD}	_	0.7	1.2	V	V _{GS} = 0V, I _S = 1A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}	_	785	_		14 0014 14 014
Output Capacitance	Coss	_	281	_	pF	$V_{DS} = 30V$, $V_{GS} = 0V$ f = 1MHz
Reverse Transfer Capacitance	C _{rss}	_	27	_		
Gate Resistance	Rg	_	1.5	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Q_{g}	_	7.3	_		
Total Gate Charge (V _{GS} = 10V)	Qg	_	13.6	_	nC	\\ - 20\\ I - 40A
Gate-Source Charge	Q_{gs}	_	2.2	_	IIC	$V_{DS} = 30V, I_D = 10A$
Gate-Drain Charge	Q_{gd}	_	3.4	_		
Turn-On Delay Time	t _{D(ON)}	_	3.2	_		
Turn-On Rise Time	t _R	_	4.4	_]	$V_{GS} = 10V, V_{DD} = 30V,$
Turn-Off Delay Time	t _{D(OFF)}	_	14.7	_	ns	$R_g = 6\Omega, I_D = 10A$
Turn-Off Fall Time	t _F	_	8.5	_	1	
Body Diode Reverse Recovery Time	t _{RR}		23.0	_	ns	1 404 11/14 4004/
Body Diode Reverse Recovery Charge	Q _{RR}		14.1	_	nC	I _F = 10A, di/dt = 100A/μs

5. Device mounted on FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout. Notes:

- 6. Device mounted on FR-4 substrate PCB, 2oz copper, with 1inch square copper plate.
- I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.







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 $T_{J}, JUNCTION\ TEMPERATURE\ (°C)$ Figure 6 On-Resistance Variation with Temperature

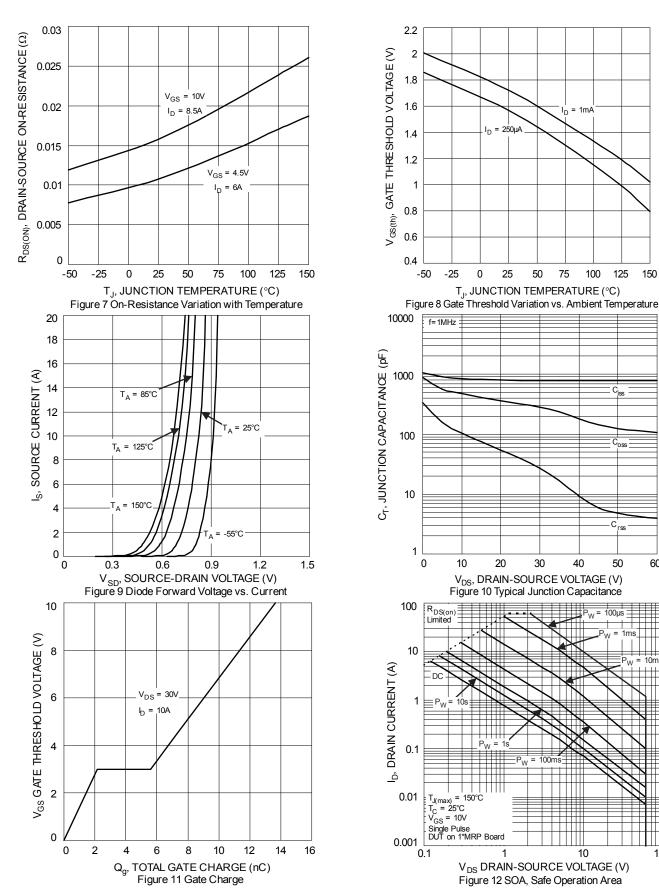
75

100

125

0.6

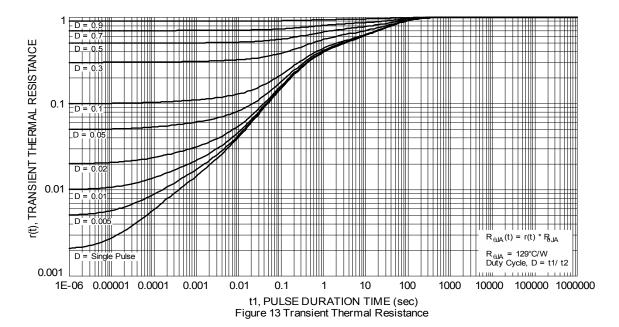




100

60



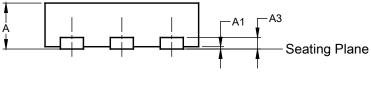


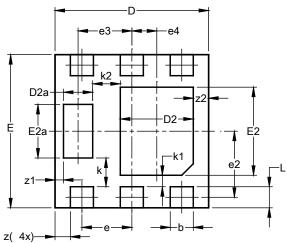


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)



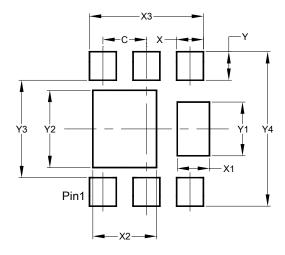


U-DFN2020-6								
	(Type F)							
Dim	Min	Max	Тур					
Α	0.57	0.63	0.60					
A1	0.00	0.05	0.03					
A3	_		0.15					
b	0.25	0.35	0.30					
D	1.95	2.05	2.00					
D2	0.85	1.05	0.95					
D2a	0.33	0.43	0.38					
Е	1.95	2.05	2.00					
E2	1.05	1.25	1.15					
E2a	0.65	0.75	0.70					
е	0.65 BSC							
e2	().863 BS	SC					
е3		0.70 BS	С					
e4	().325 BS	SC					
k		0.37 BS	С					
k1		0.15 BS	С					
k2		0.36 BS						
L	0.225	0.325	0.275					
Z	0.20 BSC							
z1	().110 BS	SC					
z2		0.20 BS	С					
All C	imens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)



Dimensions	Value (in mm)
С	0.650
X	0.400
X1	0.480
X2	0.950
Х3	1.700
Υ	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



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